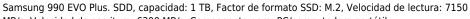
Samsung 990 EVO Plus 1 TB M.2 PCI Express 4.0 NVMe V-NAND TI C

Marca : Samsung Código del producto: MZ-V9S1T0B/AM

Nombre del producto: 990 EVO Plus



MB/s, Velocidad de escritura: 6300 MB/s, Componente para: PC/computadora portátil





Features		Power	
NVMe version Security algorithms SSD capacity * I TB SSD form factor * Interface * NVMe * Memory type * Component for * Hardware encryption * M.2 SSD size Read speed Write speed Random read (4KB) Random write (4KB) S.M.A.R.T. support Mean time between failures (MTBF) TBW rating 256-bit AES 350 A.2 350 A.2 A.2 A.3 A.3 A.3 A.3 A.4 A.5 A.5 A.6 A.5 A.6 A.6 A.6 A.6	256-bit AES L TB	Power consumption (read) Power consumption (write) Power consumption (idle)	4.3 W 4.2 W 0.06 W
	PCI Express 4.0 ✓ V-NAND TLC	Weight & dimensions Width Depth Height	80.2 mm 22.1 mm 2.38 mm
	✓ 2280 (22 x 80 mm)	Packaging data Package type Operational conditions	Hanging box
	6300 MB/s 850000 IOPS 1350000 IOPS	Operational conditions Operating temperature (T-T) Storage temperature (T-T) Operating relative humidity (H-H) Storage relative humidity (H-H) Non-operating shock	0 - 70 °C -40 - 85 °C 5 - 95% 5 - 95% 1500 G
	1500000 h	Vibration resistance Other features	20 G
		Warranty period Compliance certificates	5 year(s) CE, Federal Communications Commission (FCC), KCC

